



#10/B  
8-30-02  
RECEIVED  
Maldonado  
AUG 26 2002  
TECHNOLOGY CENTER 2800

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Tatsuya Usami

Serial No.: 09/851,313

Group Art Unit: 2823

Filed: May 9, 2001

Examiner: Maldonado, J.

For: SEMICONDUCTOR DEVICE AND SEMICONDUCTOR WAFER (Amended)

Honorable Assistant Commissioner of Patents  
Washington, D.C. 20231

**AMENDMENT UNDER 37 C.F.R. §1.111**

Sir:

In response to the Office Action dated **May 8, 2002**, please amend the above-identified application as follows:

**THE TITLE:**

✓ Please replace the original title with the following title:

SEMICONDUCTOR DEVICE AND SEMICONDUCTOR WAFER

**IN THE CLAIMS:**

✓ Please cancel claims 9-30 without prejudice or disclaimer.

Please amend the following claims:

1. (Amended) A semiconductor device comprising:

a multi-layered insulation film formed on a semiconductor substrate, said multi-layered insulation film comprising:

a first insulation layer comprising an organic material having a dielectric constant which is lower than a silicon oxide dielectric constant;

a second insulation layer comprising a polysiloxane compound having an Si-H group

B<sub>1</sub>  
sub  
C<sub>1</sub>